| Reg. No.: | | | | | | | | | | |
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Question Paper Code: 51529

B.E. / B.Tech. DEGREE EXAMINATION, NOV 2016

Second Semester

Electronics and Instrumentation Engineering

15UEI209 - ELECTRONIC DEVICES AND CIRCUITS

(Regulation 2015)

Duration: Three hours Maximum: 100 Marks

Answer ALL Questions

PART A - $(10 \times 1 = 10 \text{ Marks})$

- 1. Tunnel diode is a PN diode with
 - (a) Very high doping in p region
 - (b) Very high doping in n region
 - (c) Very high doping in both p and n region
 - (d) Low doping in both p and n region
- 2. In Schottky barrier diode, conduction is
 - (a) Entirely by electrons
 - (b) Entirely by holes
 - (c) Mainly by holes but partly by electrons
 - (d) Mainly by electrons but partly by holes
- 3. After firing an SCR, if the gate pulse is removed the SCR current.
 - (a) Remains the same

(b) Reduces to zero

(c) Rises up

(d) Rises a little and then falls to zero

- 4. The JFET can operate in
 - (a) depletion mode only
 - (b) enhancement mode only
 - (c) either depletion or enhancement mode at a time
 - (d) both depletion and enhancement modes simultaneously

| 5. | In a JFET, beyond the pinch off voltage as the drain voltage increase the drain current | | | | | | | |
|---|---|---|--|--|--|--|--|--|
| | (a) Remains almost constant | (b) Decreases | | | | | | |
| | (c) Increases | (d) May increase or decrease | | | | | | |
| 6. | The current gain of amplifier stage is lowest in | | | | | | | |
| | (a) Common base configuration | (b) Common emitter configuration | | | | | | |
| | (c) Common collector configuration | (d) Same in all configuration | | | | | | |
| 7. | The reason for cross over distortion in a push-pull amplifier is that | | | | | | | |
| | (a) the transistor are overdriven at cross over points | | | | | | | |
| | (b) switching of current from one transistor to the other | | | | | | | |
| | | stic of the two transistors is most nonlinear at | | | | | | |
| | zero base current | | | | | | | |
| | (d) the input signals rise fast at their | zeros | | | | | | |
| 8. | In the Barkhausen criterion, the loop ga | in A is equal to | | | | | | |
| | (a) ∞ (b) 200,000 | (c) 0 (d) 1 | | | | | | |
| 9. Mono-stable multi vibrator may be used to generate | | | | | | | | |
| | (a) Sweep voltage | (b) Pulses | | | | | | |
| | (c) Sinusoidal voltage | (d) Sweep current | | | | | | |
| 10. | Schmitt trigger is also known as | | | | | | | |
| | (a) Squaring circuit | (b) Sweep circuit | | | | | | |
| | (c) Blocking oscillator | (d) Astable multivibrator | | | | | | |
| | PART - B (| $5 \times 2 = 10 \text{ Marks}$ | | | | | | |
| 11. | What is meant by Zener breakdown? | | | | | | | |
| 12. | How the MOSFET does has high input | impedance? | | | | | | |
| 13. | List out the characteristics of CE amplif | ier. | | | | | | |
| 14. | In the Hartley oscillator $L_2 = 0.4$ mH a oscillator is 120KHz, find the value of I | and $C = 0.004$ micro farad. If the frequency of the L_1 . Neglect the mutual inductance. | | | | | | |
| 15. | Give two applications of bistable multiv | vibrator. | | | | | | |
| | * * | | | | | | | |

PART - C (5 x 16 = 80 Marks)

16. (a) Discuss the construction and operation of a tunnel diode with a neat energy band diagram. (16)

| | (b) | (i) What is thermal runaway? Derive the necessary condition to avoid the thermal runaway. (8) |
|-----|-----|---|
| | | (ii) Explain the operation of NPN and PNP transistor with neat diagram. (8) |
| 17. | (a) | (i) Explain the transfer characteristics and drain characteristics of JFET. (10) |
| | | (ii) In a n-channel JFET I_{DSS} =2 mA and V_P = -6V. Calculate the drain Current when V_{GS} = -3V. (6) |
| | | Or |
| | (b) | With neat diagram, explain the operation, VI characteristics and transfer characteristics of N-channel depletion type MOSFET. (16) |
| 18. | (a) | Draw the hybrid- π common emitter transistor model and derive the values of the various components in terms of the h-parameters. (16) |
| | | Or |
| | (b) | (i) Derive the equation for efficiency of a class B amplifier. (8) |
| | | (ii) What is cross over distortion? How it can be minimized. (8) |
| 19. | (a) | (i) Draw the circuit diagram of a Wein bridge oscillator and briefly explain its operation. (8) |
| | | (ii) In an RC phase shift oscillator if R1=R2=R3=200Kohm and C1=C2=C3=100PF. Find the frequency of the oscillation. (8) |
| | | Or |
| | (b) | Describe Hartley oscillator with neat circuit diagram. Determine the frequency of oscillations and the oscillation conditions for it. (16) |
| 20. | (a) | What is multivibrator? On what basis are multivibrators classified? With neat sketch explain the working of an Astable multivibrator. (16) |
| | | Or |
| | (b) | With the circuit details, explain the operation of a Schmitt trigger using transistors. Show how Schmitt trigger can be used for wave shaping purposes. List out the application of Schmitt trigger. (16) |